## NSN 5961-01-312-1891

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-312-1891 **Inclosure Material:** Glass **Overall Length:** Between 0.064 inches and 0.104 inches **Terminal Length:** 0.150 inches **Overall Height:** Between 0.026 inches and 0.034 inches **Overall Width:** Between 0.064 inches and 0.104 inches **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 0.13 forward voltage, dc and 0.35 reverse voltage, instantaneous **Current Rating Per Characteristic:** 0.175 milliamperes service voltage and 0.225 milliamperes source cutoff current **Capacitance Rating In Picofarads:** 0.75 **Maximum Operating Tempurature Per Measurement Point:** 115.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**